

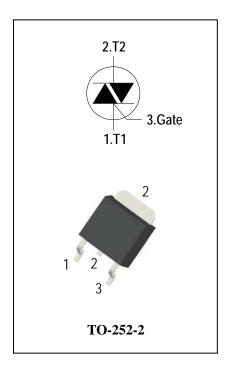
4Quadrants Triacs

General Description

High current density due to mesa technology . the ADS6D triac series is suitable for general purpose AC switching. They can be used as an ON/OFF function in applications such as static relays, heating regulation, High power motor controls e.g. washing machines and vacuum cleaners,Rectifier-fed DC inductive loads e.g.DC motors and solenoids , motor speed controllers.

Features

- ◆ Repetitive Peak Off-State Voltage: 600Vand800V
- ◆ R.M.S On-State Current (I_{T(RMS)}= 6A)
- ◆ High Commutation dv/dt
- ◆ These Devices are Pb-Free and are RoHS Compliant



Absolute Maximum Ratings

Symbol	Items	Conditions		Ratings	Unit
V_{DRM}	Denotitive Deak Off State Valtage	T: - 25°C	ADS6D60	600	V
V_{RRM}	Repetitive Peak Off-State Voltage	Tj = 25°C	ADS6D80	800	V
$I_{T(RMS)}$	R.M.S On-State Current	T _C = 110 °C		6	Α
I _{TSM}	Surge On-State Current	tp=20ms(50Hz)/tp=16.7ms(60Hz)		60/63	А
l ² t	I ² t for fusing	tp=10ms		20	A ² s
-11/-14	Critical rate of rise of on-state	F = 120 Hz Tj = 125°C		50	A /
dl/dt	current	$I_G = 2 \times I_{GT}$, tr $\leq 100 \text{ ns}$		50	A/μs
I_{GM}	Peak Gate Current	tp = 20 μs Tj = 125°C		4	Α
$P_{G(AV)}$	Average Gate Power Dissipation(Tj=125°C)			1	W
P_GM	Peak Gate Power Dissipation(tp=20us,Tj=125°C)			5	W
Tj	Operating Junction Temperature			- 40 ~ 125	°C
T _{STG}	Storage Temperature			- 40 ~ 150	°C



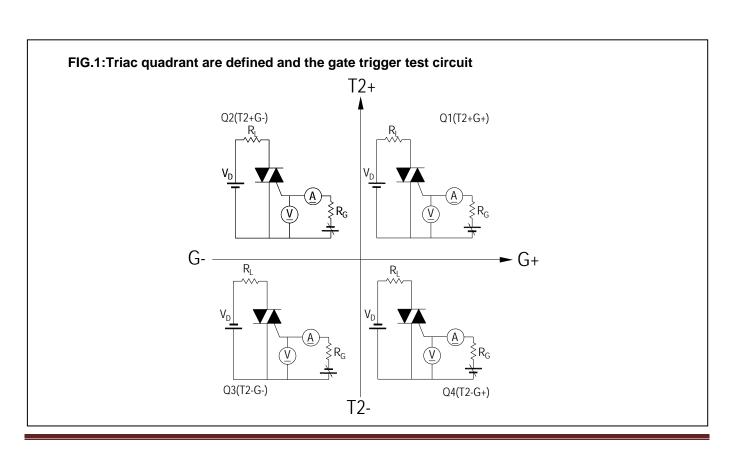


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Electrical Characteristics (Tj = 25°C unless otherwise specified)

Symbol	Items	Conditions		ADS6D60E/80E			Unit		
					Т	S	Blank	В	
I _{DRM}	Peak Forward Reverse Blocking		$V_{DRM} = V_{RRM}, T_{J} = 25^{\circ}C$	May	5			uA	
I _{RRM}	Current		$V_{DRM} = V_{RRM}, T_J = 125^{\circ}C$	Max.	1			mA	
V_{TM}	Peak On-Sta	ite Voltage	I_{TM} = 8.5A, t_p = 380 μ s	Max.	1.55			V	
V_{GD}	Q1-Q2-Q3-Q4	Non – Trigger Gate Voltage	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $T_J = 125^{\circ}\text{C}$	Min.	0.2		V		
V_{GT}	Q1-Q2-Q3-Q4	GateTrigger Voltage		Max.	1.3		V		
	Q1-Q2-Q3	GateTrigger Current	$V_D = 12V$, $R_L = 33\Omega$	Max.	5	10	35	50	mA
I _{GT}	Q4				10	25	70	100	
lΗ	Q1-Q2-Q3-Q4	Holding Current	I _T = 0.1A	Max.	10	25	35	60	mA
	Q1-Q3-Q4	Latabina Cumant	1 - 401	May	T S	30	40	60	mA
l _L	Q2	Latching Current	I _G = 1.2 I _{GT}	Max.		40	60	90	
dV/dt	Critical Rate of Rise of Off-State Voltage		$V_D = 2/3V_{DRM}$ gate open $Tj = 125^{\circ}C$	Min.	10	20	200	400	V/µs
(dV/dt)c	Rate of Change of Commutating Current,		(dl/dt)c=-2.7A/ms Tj = 125°C	Min.	1	2	5	10	V/µs
R _{th(j-c)}	Junction to case (AC)		Max.	1.8			°C/W		
R _{th(j-a)}	Junction to ambient(Copper surface under tab:S=0.5cm²)		Max.	70			°C/W		



ADV

FIG.2: Maximum on-state power dissipation

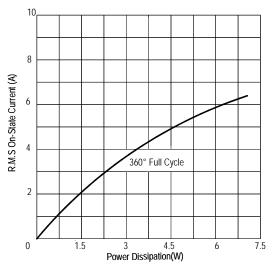


FIG.4: Maximum transient thermal impedance

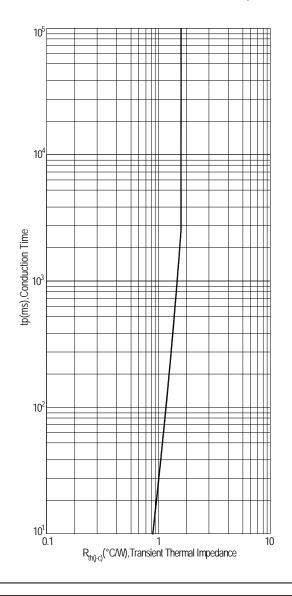


FIG.3: Typical RMS on-state current VS Allowable case Temperature

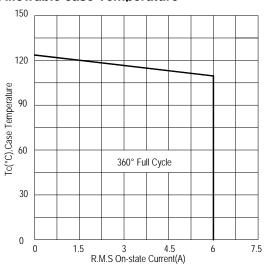


FIG.5: Rated surge on-state current (Non-Repetitive)

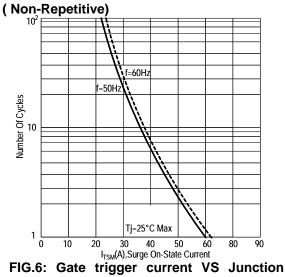


FIG.6: Gate trigger current VS Junction temperature

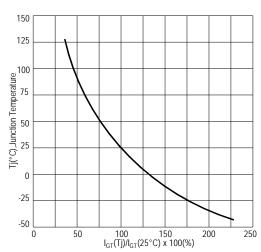




FIG.7:Holding current and Latching current VS Junction temperature

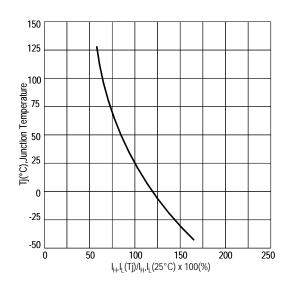


FIG.8: Gate trigger voltage VS Junction temperature

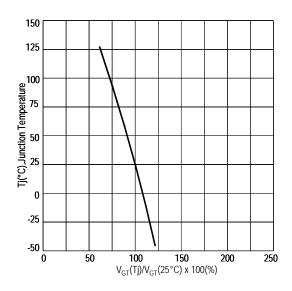
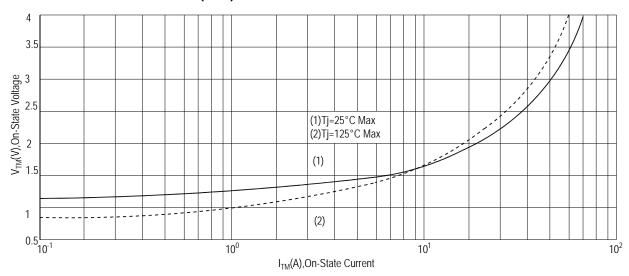
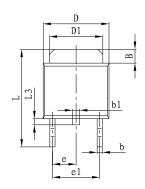


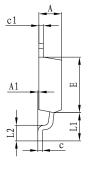
FIG.9: On-state characteristics(Max)

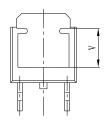




PACKAGE MECHANICAL DATA TO-252-2 Package Dimension

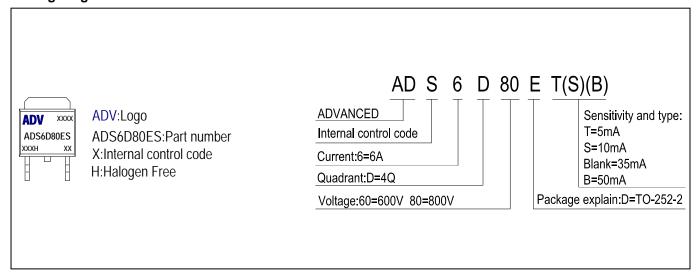






Cross	Dimensions		Dimensions		
Symb	In Milli	meters	In Inches		
ol	Min.	Max.	Min.	Max.	
Α	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
В	1.350	1.650	0.053	0.065	
b	0.500	0.700	0.020	0.028	
b1	0.700	0.900	0.028	0.035	
С	0.450	0.620	0.017	0.024	
c1	0.450	0.620	0.017	0.024	
D	6.350	6.650	0.250	0.262	
D1	5.100	5.400	0.200	0.213	
Е	5.900	6.200	0.232	0.244	
е	2.300 TYP.		0.091 TYP.		
e1	4.500	4.700	0.177	0.185	
L	9.500	10.60	0.374	0.396	
L1	2.550	2.900	0.100	0.114	
L2	1.400	1.780	0.055	0.070	
L3	0.600	0.900	0.024	0.035	
V	4.100	REF.	0.161 REF.		

Making Diagram



Ordering information

Part number	ımber Package Marking Packing		Quantity			
ADS6D60E#	TO-252-2	ADS6D60E#	Tube	80pcs		
ADS0D00E#			Embossed tape	2500pcs		
AD00D00E#	TO-252-2	ADS6D80E#	Tube	80pcs		
ADS6D80E#			Embossed tape	2500pcs		
Note:# = Gate Trigger Current Sensitivity and type						



ADS6D60E/80E

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